

Complementary power Darlington transistors

Features

- Low collector-emitter saturation voltage
- Integrated antiparallel collector-emitter diode

Applications

■ General purpose linear and switching

Description

The devices are manufactured in planar technology with "base island" layout and monolithic Darlington configuration. The resulting transistors show exceptional high gain performance coupled with very low saturation voltage.

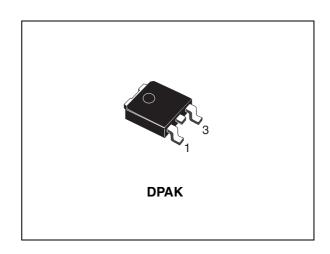


Figure 1. Internal schematic diagrams

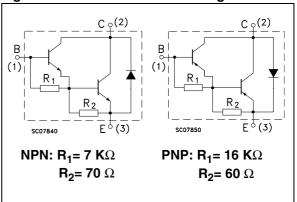


Table 1. Device summary

Order codes	Marking	Polarity	Package	Packaging
MJD122T4	MJD122	NPN	DPAK	Tape and reel
MJD127T4	MJD127	PNP	DFAR	Tape and Teel

Content MJD122, MJD127

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MJD122, MJD127 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage (I _E = 0)	100	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	100	V
V _{EBO}	Emitter-base voltage ($I_C = 0$)	5	V
I _C	Collector current	8	Α
I _{CM}	Collector peak current	16	Α
I _B	Base current	0.12	Α
P _{TOT}	Total dissipation at T _{case} = 25°C	20	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Note: For PNP types voltage and current values are negative.

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-c}	Thermal resistance junction-case max.	6.25	°C/W

Electrical characteristics MJD122, MJD127

2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C; \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 100 V		-	10	μА
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CE} = 50 V		-	10	μА
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V		-	2	mA
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C = 30 mA	100	ı		V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_C = 4 \text{ A}$ $I_B = 16 \text{ mA}$ $I_C = 8 \text{ A}$ $I_B = 80 \text{ mA}$		-	2 4	V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 8 A I _B = 80 mA		ı	4.5	V
V _{BE(on)} ⁽¹⁾	Base-emitter on voltage	$I_C = 4 A$ $V_{CE} = 4 V$		-	2.8	V
h _{FE} ⁽¹⁾	DC current gain	$I_{C} = 4A \qquad V_{CE} = 4 V$ $I_{C} = 8 A \qquad V_{CE} = 4 V$	1000 100	-	12000	

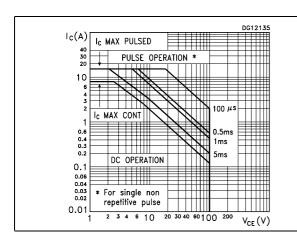
^{1.} Pulsed duration = 300 μ s, duty cycle \leq 1.5%

Note: For PNP types voltage and current values are negative.

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve



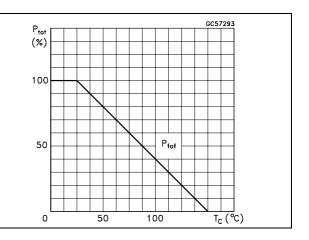
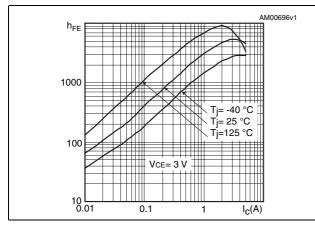


Figure 4. DC current gain for NPN type

Figure 5. DC current gain for PNP type



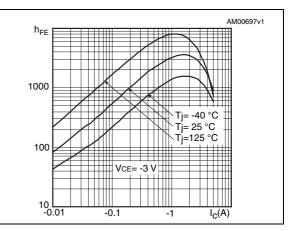
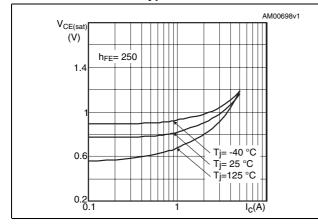
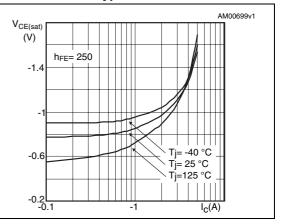


Figure 6. Collector-emitter saturation voltage Figure 7. Collector-emitter saturation voltage for NPN type





Electrical characteristics MJD122, MJD127

Figure 8. Base-emitter saturation voltage for Figure 9. Base-emitter saturation voltage for NPN type PNP type

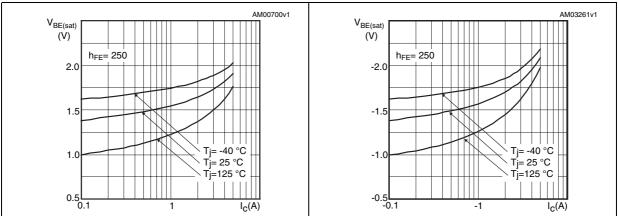


Figure 10. Base-emitter on voltage for NPN type

Figure 11. Base-emitter on voltage for PNP type

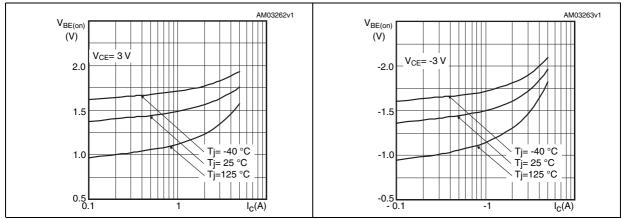
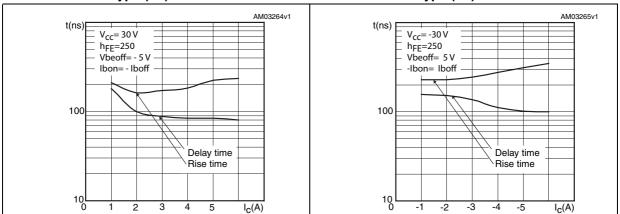


Figure 12. Resistive load switching times for NPN type (on)

Figure 13. Resistive load switching times for PNP type (on)



MJD122, MJD127 Electrical characteristics

Figure 14. Resistive load switching times for NPN type (off) Figure 15. Resistive load switching times for PNP type (off)

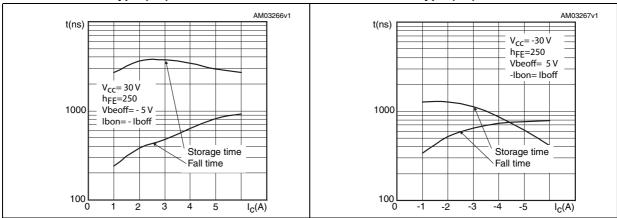
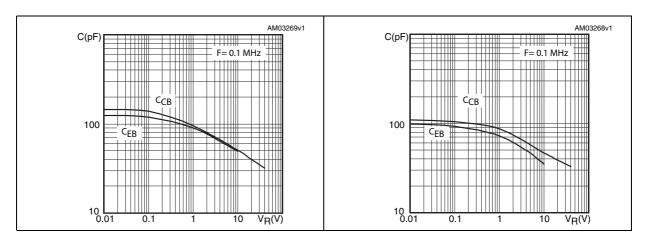


Figure 16. Capacitances for NPN type

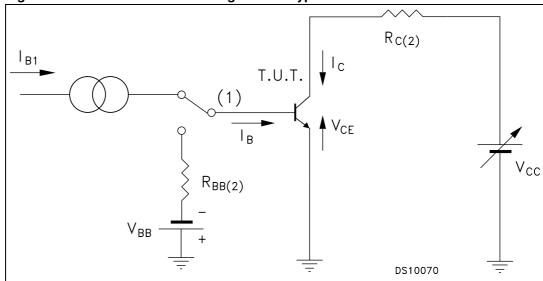
Figure 17. Capacitances for PNP type



Test circuits MJD122, MJD127

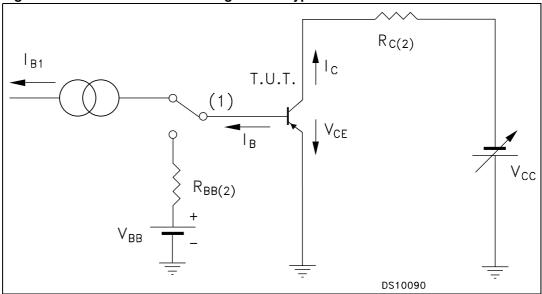
3 Test circuits

Figure 18. Resistive load switching for NPN type



- 1. Fast electronic switch
- 2. Non-inductive resistor

Figure 19. Resistive load switching for PNP type



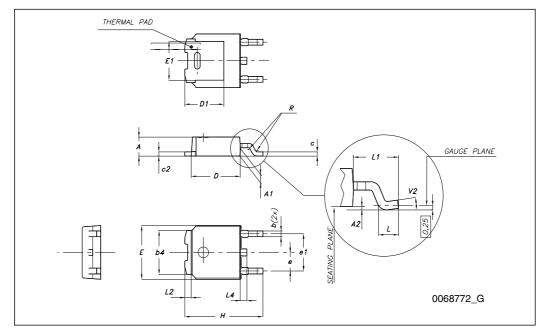
- 1. Fast electronic switch
- 2. Non-inductive resistor

4 Package mechanical data

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TO-252 (DPAK) mechanical data

DIM.		mm.	
DIIVI.	min.	typ	max.
Α	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 °



MJD122, MJD127 Revision history

5 Revision history

Table 5. Document revision history

Date	Revision	Changes
01-Aug-2002	8	
01-Oct-2007	9	Collector current limits have been improved
03-Oct-2007	10	Package mechanical data updated
21-Apr-2009	11	The device MJD127 has been inserted Section 2.1: Electrical characteristics (curves) has been updated

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